

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	13997	(electrode terminal pad) same (polycrystalline polycrystal) same (transition metal grain crystal platinum pt nickel ni palladiu, pd chromium cr iron fe)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 15:40
L2	2786	1 same ((P with type) ptype)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 15:45
L3	4	((group with iii) with nitride) same 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 15:42
L4	1272	2 and nitride	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 15:46
L5	36	4 and (gan algan gainn)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 15:48

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	18478	(die chip dice semiconductor ic (integrated adj circuit)) with (peripheral edge border) with (lead terminal wiring)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 13:49
L3	922564	(hold holding holded retain retaining retained) with "1"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 13:50
L4	549	(hold holding holded retain retaining retained) with 2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/05/13 13:50